



November 2, 2010

RF Micro Devices(R) to Showcase Industry-Leading High Performance RF Components at electronica 2010

RFMD's Expanded Multi-Market Product Portfolio Supports Broad End Market Growth

GREENSBORO, N.C., Nov 2, 2010 (GlobeNewswire via COMTEX News Network) -- RF Micro Devices, Inc. (Nasdaq:RFMD), a global leader in the design and manufacture of high-performance semiconductor components and compound semiconductor technologies, today announced it will showcase the Company's industry-leading high-performance RF components at electronica 2010, in Munich from November 9 to November 12, 2010.

RFMD continues to expand its portfolio of products and technologies for the wireless and wired broadband markets in support of broad end-market growth. RFMD's high performance RF components serve over 20 end-market segments, including point-to-point (P2P) microwave radio, high performance WiFi, WiMax, smart energy, wireless infrastructure, military and space, broadband transmission, and wireless consumer products.

Of note, the high-performance products on display at electronica 2010 will include RFMD's breakthrough GaN-based products, such as the RF3932 -- a DC to 3GHz 78-Watt unmatched power transistor for high-power applications, and RFMD's recently announced RFPD2650 hybrid power doubler amplifier for CATV infrastructure applications. RFMD will also display its newly released RFSA2614 and RFSA2624 digital step attenuators, which address 3G/4G/LTE and WiMax markets, and the RF6535 - a single-chip ZigBee front end module (FEM) that is optimized specifically for smart energy and advanced metering infrastructure (AMI) applications including smart meters.

RFMD's product portfolio will be on display at the electronica 2010 November 9 to November 12, Stand #A4.136.

About RFMD

RF Micro Devices, Inc. (Nasdaq:RFMD) is a global leader in the design and manufacture of high-performance semiconductor components. RFMD's products enable worldwide mobility, provide enhanced connectivity and support advanced functionality in the cellular handset, wireless infrastructure, wireless local area network (WLAN), CATV/broadband and aerospace and defense markets. RFMD is recognized for its diverse portfolio of semiconductor technologies and RF systems expertise and is a preferred supplier to the world's leading mobile device, customer premises and communications equipment providers.

Headquartered in Greensboro, N.C., RFMD is an ISO 9001- and ISO 14001-certified manufacturer with worldwide engineering, design, sales and service facilities. RFMD is traded on the NASDAQ Global Select Market under the symbol RFMD. For more information, please visit RFMD's web site at www.rfmd.com.

The RF Micro Devices, Inc. logo is available at <http://www.globenewswire.com/newsroom/prs/?pkgid=6436>

This press release includes "forward-looking statements" within the meaning of the safe harbor provisions of the Private Securities Litigation Reform Act of 1995. These forward-looking statements include, but are not limited to, statements about our plans, objectives, representations and contentions and are not historical facts and typically are identified by use of terms such as "may," "will," "should," "could," "expect," "plan," "anticipate," "believe," "estimate," "predict," "potential," "continue" and similar words, although some forward-looking statements are expressed differently. You should be aware that the forward-looking statements included herein represent management's current judgment and expectations, but our actual results, events and performance could differ materially from those expressed or implied by forward-looking statements. We do not intend to update any of these forward-looking statements or publicly announce the results of any revisions to these forward-looking statements, other than as is required under the federal securities laws. RF Micro Devices' business is subject to numerous risks and uncertainties, including variability in operating results, risks associated with the impact of global macroeconomic and credit conditions on our business and the business of our suppliers and customers, our reliance on a few large customers for a substantial portion of our revenue, the rate of growth and development of wireless markets, our ability to bring new products to market, our reliance on inclusion in third party reference designs for a portion of our revenue, our ability to manage channel partner and customer relationships, risks associated with the operation of our wafer fabrication, molecular beam epitaxy, assembly and test and tape and reel facilities, our ability to complete acquisitions and integrate acquired companies, including the risk that we may not realize expected synergies from our business combinations, our ability to attract and retain skilled personnel and develop leaders, variability in production yields, raw material costs and availability, our ability to reduce costs and improve margins in response to declining average selling prices, our ability to adjust production capacity in a timely fashion

in response to changes in demand for our products, dependence on gallium arsenide (GaAs) for the majority of our products, dependence on third parties, and substantial reliance on international sales and operations. These and other risks and uncertainties, which are described in more detail in RF Micro Devices' most recent Annual Report on Form 10-K and other reports and statements filed with the Securities and Exchange Commission, could cause actual results and developments to be materially different from those expressed or implied by any of these forward-looking statements.

RF MICRO DEVICES(R) and RFMD(R) are trademarks of RFMD, LLC. All other trade names, trademarks and registered trademarks are the property of their respective owners.

This news release was distributed by GlobeNewswire, www.globenewswire.com

SOURCE: RF Micro Devices

CONTACT: RF Micro Devices
Douglas DeLieto, VP of Investor Relations
336-678-7088

(C) Copyright 2010 GlobeNewswire, Inc. All rights reserved.

News Provided by COMTEX